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Article *in* Applied Physics B · June 2009 DOI: 10.1007/s00340-009-3544-6



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Effect of co-sensitization in new hybrid photo-refractive materials based on PVK polymer matrix and inorganic LiNbO₃ nano-crystals

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Received: 20 February 2009 / Revised version: 29 March 2009 / Published online: 2 May 2009 © Springer-Verlag 2009

Abstract A new class of photo-refractive (PR) composite materials based on poly(*N*-vinylcarbazole) (PVK) (co-) sensitized with nano-crystalline lithium niobate (LiNbO₃) is presented. The steady-state performance, as well as the kinetics of the photo-refractive grating formation, was investigated by degenerate four-wave mixing (DFWM) and twobeam-coupling (TBC) experiments. We found an optimum content of LiNbO₃ nano-particles of only 10^{-3} wt.%. Even at concentrations as low as 10^{-7} wt.% a notable effect of the nano-crystals was detected. This yields materials with improved PR performance compared to that of the standard PR polymer material sensitized by TNF only. The role of LiNbO₃ nano-particles is discussed in detail: The particles support generation and transport of the free-charge carriers. Furthermore, they increase the electron trap density.

PACS 77.84.Nh · 78.67.Bf · 81.07.-b

1 Introduction

The photo-refractive (PR) effect, discovered in 1966 in $LiNbO_3$ [1], is considered today to be one of the most

U. Hartwig · K. Buse Institute of Physics, University of Bonn, Wegelerstr. 8, 53115 Bonn, Germany promising mechanisms for many potential holographic applications, including real-time image processing, phase conjugation, and selective laser feedback, because the writing process is reversible and requires only low light intensities [2]. In a PR material holograms can be stored as modulations of the refractive index using light sources of relatively low power (e.g., laser diodes). In 1991, the PR effect was observed for the first time in a polymer [3]. This discovery initiated intense research efforts. Following various design concepts, a huge number of new PR polymers has been developed and their PR properties improved rapidly [4–8].

One class of PR materials are the hybrid composites consisting of inorganic nano-particles embedded into a polymer matrix [9–11]. This contribution reports on a novel class of PR materials combining the most studied organic and inorganic PR systems. They consist of lithium niobate (LiNbO₃) nano-particles (NP) embedded into an amorphous PR polymer composite derived from the first highperformance PR polymer based on the photo-conductor poly(N-vinylcarbazole) (PVK) [4, 12]. We expect that the nano-crystal/polymer hybrid materials offer additional advantages over the existing photo-refractive materials, e.g., a faster response, a broad-band spectral sensitivity, and new photo-refractive properties. In a previous study we incorporated LiNbO₃ NP into PVK and found that the drift length of free holes is enlarged due to trapping of electrons by the LiNbO3 nano-particles and therefore increased recombination time of the free holes [13]. These results encouraged us to employ the LiNbO3 NP also in a PR hybrid material that also contains-in addition to the material studied in Ref. [13]-electro-optic chromophores.

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Fig. 1 Chemical structures of the compounds used in this study



2 Experimental methods

The components of the composite materials studied in this paper contained the photo-conductor PVK, the plasticizer *N*-ethylcarbazole (ECZ), the chromophores 2,5-dimethyl-4-*p*-nitrophenylazoanisole (DMNPAA) and 3-methoxy-4-*p*-nitrophenylazoanisole (MNPAA), the sensitizers 2,4,7-trinitro-9-fluorenone (TNF), and LiNbO₃ NP. The chemical structures of the compounds are depicted in Fig. 1. PVK and ECZ were purchased from Aldrich, the DMNPAA and MNPAA were synthesized by standard azo coupling of the appropriate subunits. The LiNbO₃ NP was prepared by following a procedure published earlier [14]. The size of the NP was about 20 nm in diameter.

For mixing, all components were dissolved in dichloromethane, and the solvent was then allowed to evaporate. Uniform films were fabricated by sandwiching the composite between two transparent indium–tin-oxide-coated glass substrates at elevated temperature using glass spacer beads to adjust the film thickness to $d = 105 \mu m$. All devices, also those containing NP's, exhibited excellent optical quality.

Two series of materials were prepared (Table 1): In the first series (A–I), the concentration of the standard sensitizer TNF was 1 wt.% and different amounts of LiNbO₃ NPs (from 10^{-7} to 2 wt.%) were added. The reference material R did not contain LiNbO₃. In the second series (A'–I'), the content of LiNbO₃ was again varied (from 10^{-7} to 2 wt.%), however, in the absence of TNF. The reference material R' did neither contain LiNbO₃ nor TNF.

Materials with low contents of LiNbO₃ (from 10^{-7} to 10^{-3} wt.%) were prepared by diluting the composite with higher content by 1:100, while the higher amounts of LiNbO₃ (from 10^{-1} to 2 wt.%) were directly added to the composite. The glass-transition temperature T_g was investigated by differential scanning calorimetry in selected cases (heating rate of 10 K min⁻¹). The obtained T_g started from 16°C in the absence of NP (materials A and A') and was slightly lowered by the presence of the NP, reaching 13°C

Table 1 The sensitizer contents in the investigated materials (wt.%) are listed. The other components were 41.5 wt.% PVK, 7.5 wt.% ECZ, 25 wt.% DMNPAA, and 25 wt.% MNPAA, respectively. Furthermore, the glass-transition temperatures (T_g) measured by DSC are listed

Composites	Sensitizers		$T_{\rm g}/^{\circ}{\rm C}$
	TNF	LiNbO ₃	
R	1.0	0	16
А	1.0	10^{-7}	
В	1.0	10^{-5}	
С	1.0	10^{-3}	15
D	1.0	0.1	
Е	1.0	0.2	
F	1.0	0.5	
G	1.0	1.0	
Н	1.0	1.5	
Ι	1.0	2.0	13
R′	0	0	16
A′	0	10^{-7}	
Β′	0	10^{-5}	
C′	0	10^{-3}	
D′	0	0.1	
E'	0	0.2	
F'	0	0.5	14
G'	0	1.0	
H′	0	1.5	
I'	0	2.0	13

for materials I and I' with the maximum amount of NP (Table 1). Samples with LiNbO₃ NP particle contents exceeding 2 wt.% showed clearly light scattering, samples with NP concentrations below 1 wt.% exhibited no scattering at all.

The photo-conductive properties of the composites were studied by a modulated photo-current technique. In these experiments the DC-biased sample was homogeneously illuminated by HeNe laser light ($\lambda_0 = 632.8$ nm) whose inten-

sity was periodically varied with the frequency $\Omega = 10$ Hz. A time modulated photo-conductivity is created and application of an external electric field yields the modulated photocurrent. The photo-current was detected by an SRS 830 lock-in amplifier with $R_L = 10 \text{ M}\Omega$ input resistance.

The PR properties were investigated at $T = 21^{\circ}$ C by degenerate four-wave mixing (DFWM) and two-beamcoupling (TBC) experiments in a tilted geometry (tilt angle $\psi_{ext} = 60^{\circ}$) using a HeNe laser. The writing beams (1 and 2, respectively) were s-polarized, the external beam angles were $\alpha_{1,ext} = 50^{\circ}$ and $\alpha_{2,ext} = 70^{\circ}$, and the external intensities were $I_{1,ext} = 340 \text{ mW cm}^{-2}$ and $I_{2,ext} =$ 930 mW cm⁻², respectively. Considering the reflection losses, this ensures equal internal intensities (grating contrast $m \approx 1$). The recorded grating was read by an independent weak p-polarized reading beam ($I_{R,ext} = 3 \text{ mW cm}^{-2}$) [4].

The internal diffraction efficiency η_{int} is defined as the ratio between the intensity of the diffracted light and the overall light intensity behind the sample, i.e., the sum of the intensities of the diffracted and transmitted beams, $I_{R,\text{diff}}$ and $I_{R,\text{trans}}$, respectively [15]:

$$\eta_{\rm int} = \frac{I_{R,\rm diffr}}{I_{R,\rm diffr} + I_{R,\rm transm}}.$$
(1)

According to the coupled-wave theory [16], η_{int} can be approximated by

$$\eta_{\text{int}} = \sin^2(\nu) \quad \text{with } \nu = C_{\text{DFWM}} \Delta n,$$
 (2)

where $C_{\text{DFWM}} = \pi d / [\lambda_0 \cos(\alpha_{1,\text{int}})]$ is a constant that contains, among other things, the thickness of the sample *d*, the angle of incidence of the probe beam $\alpha_{1,\text{int}}$ inside the sample, and the probe-beam vacuum wavelength λ_0 . Here Δn is the index modulation amplitude of the recorded hologram.

Generally, for organic PR materials, in DFWM experiments the diffraction efficiency η_{int} increases with increasing external field and reaches a maximum for a specific field value $E_{(\eta \text{ max})}$ [4, 12]. This means that the argument ν of the function describing the diffraction efficiency (Eq. 2) becomes $\nu = \pi/2$. Since the recording geometry is identical in all cases, the index modulation amplitude Δn is always the same at $E_{(\eta \text{ max})}$ (over-modulation field). The latter can, therefore, be regarded as a convenient parameter characterizing the PR performance of a material [17]: the lower $E_{(\eta \text{ max})}$ for a given composite, the higher is Δn at any given external field and the better is its PR performance.

The PR two-beam coupling (TBC) gain Γ was calculated according to [15]

$$\Gamma = \frac{1}{d} \left[\cos \alpha_{1,\text{int}} \ln \left(\frac{I_1(E)}{I_1(E=0)} \right) - \cos \alpha_{2,\text{int}} \ln \left(\frac{I_2(E)}{I_2(E=0)} \right) \right],$$
(3)

where $\alpha_{1(2),\text{int}}$ are the angles of the writing beams with regard to the sample normal measured inside the material, $I_{1,2}(E)$ are the intensities of the writing beams behind the sample at some applied electric field *E*, and *d* is the thickness of the active layer.

The field-dependent steady-state data were determined by gradually increasing the applied voltage in steps of 250 V. To allow the systems to reach quasi-steady-state conditions, the data were taken with a 90 s time interval between each step. For the dynamic measurements, the samples were illuminated by the 1 writing beam for 600 s without an electric field applied. Then the devices were poled for 120 s by applying an electric field of $E = 43 \text{ V} \mu \text{m}^{-1}$. During that time, which was sufficiently long enough to reach the quasisteady state for poling, the sample was illuminated uniformly by beam 1. To start the recording, a magnetic shutter switched the second writing beam on. Data collection started 10 ms prior to the switching. The recording process is rather complicated (e.g., space-charge field formation and chromophore orientation take place simultaneously), and thus throughout the following discussion the time necessary to achieve 50% of the quasi-steady-state diffraction efficiency (measured after 300 s), $\tau_{50}^{\rm r}$, was chosen as a phenomenological metric of comparison for the recording data. Similarly, the time necessary to erase the gratings by the writing beam 2 to 50% of their previous strength, τ_{50}^{e} , will be quoted.

3 Experimental results

3.1 Photo-current measurements

The electric field dependences of the photo-current amplitude j_{ph}^{Ω} are depicted in Fig. 2 for selected materials (R/A/C/I and R'/A'/C'/I', respectively). The plots for the other samples with intermediate concentrations of NP are in between-showing all data would overload Fig. 2. We found that the field dependence of j_{ph}^{Ω} is super-linear in all cases, indicating geminate recombination typical for polymeric photo-conductors [18, 19]. The photo-current amplitude j_{ph}^{Ω} increases sub-linearly with the LiNbO₃ content and is more than one order of magnitude larger for the materials containing TNF than for those without TNF at identical LiNbO₃ content. This is expected since TNF is the sensitizer commonly used with PVK [4-6]. In the reference material R' we find that j_{ph}^{Ω} does not vanish, i.e., charge generation processes take place even in the absence of TNF. Furthermore, a sample which contains only PVK and LiNbO₃ NP (without chromophores and without TNF) does not exhibit any photo-current (not shown).

3.2 Steady-state PR performance

The PR properties of the two series of materials show a similar dependence of the steady-state PR performance on the



Fig. 2 External-DC-field dependence of the photo-current signal for different concentrations of LiNbO₃ nano-particles: material R (*solid squares*), material A (*solid circles*), material C (*solid triangles*), and material I (*solid rhombus*); material R' (*open squares*), material A' (*open circles*), material C' (*open triangles*), and material I' (*open rhombus*)

NP content both for DFWM and TBC. Figure 3a presents the field strength necessary to reach the electric field for over-modulation of the diffraction, $E_{(\eta \text{ max})}$, as a function of the LiNbO₃ nano-particle concentration. For comparison, $E_{(\eta \text{ max})}$ of the reference material R is indicated by a solid line. The second reference material R' did not show any photo-refractivity under the conditions described earlier in the article (can be seen only on much longer time scales [20, 21]). For the materials containing TNF (A–I), $E_{(\eta \text{ max})}$ is generally smaller by about 10 V/µm than for the materials without TNF, but identical LiNbO₃ content (A'–I'). Within one series, the best PR performance (lowest $E_{(\eta \text{ max})}$) has been obtained with the material sensitized with 10⁻³ wt.% LiNbO₃ (C and C'). In both series the best material is superior to the reference material (R and R'), respectively.

Figure 3b shows the dependence of the TBC gain coefficient Γ_s on the LiNbO₃ nano-particle concentration. The DC-field value that corresponds to maximum diffraction in the best material C (47.25 V μ m⁻¹) was selected for comparison purposes. The gain reaches the highest values at a LiNbO₃ content of 10⁻³ wt.%. For the materials, sensitized with LiNbO₃ only (A–I), the gain is consistently larger than in the material co-sensitized with TNF (A'–I'). Since the opposite holds for the index modulation Δn (it is larger in the series A–I as compared to series A'–I'), we conclude that the photo-refractive phase shift is reduced in the materials



Fig. 3 Dependence of the field of maximum diffraction in DFWM experiments $E_{(\eta \max)}$ (**a**) and the gain coefficient for s-polarized beams Γ_s measured at 47.25 V μ m⁻¹ (**b**) on the concentration of LiNbO₃ nano-particles: materials sensitized with TNF and LiNbO₃ (A–I, *solid symbols*), materials sensitized with LiNbO₃ only (A'–I', *open symbols*). The *thick solid lines* indicate the performance of the reference material R. All *other lines* are guides to the eye

containing TNF (A–I) as compared with the series without TNF (series A'-I').

3.3 Dynamic PR performance

The time-resolved diffraction efficiencies upon recording and erasure were measured according to the scheme described in the experimental section. The results are shown in Fig. 4. Both recording and erasure are faster by about one order of magnitude in the materials sensitized with TNF (A–I) compared to those not containing TNF (A'–I'). In both groups of materials erasure is faster than recording by a factor of 2–3. The recording/erasure speed is only slightly affected by changes of the NP content; the variations within one series of materials are less than a factor of 2.

4 Discussion

Our experimental data allow drawing conclusions about the role of LiNbO₃ NP on space-charge formation in this hybrid material. Here, we put forward a scheme explaining the



Fig. 4 Holographic response times during recording τ_{50}^{r} (*squares*) and erasure τ_{50}^{e} (*circles*) for the materials sensitized with TNF and LiNbO₃ (A–I, *solid symbols*) and materials sensitized with LiNbO₃ only (A'–I', *open symbols*) obtained at 43 V µm⁻¹. The *thick solid (dashed) line* indicates τ_{50}^{r} (τ_{50}^{e}) for the reference material R

energetic situation (Fig. 5). Our previous results indicated that the LiNbO₃ conduction band (CB) edge lies below the lowest unoccupied molecular orbital (LUMO) level of the sensitizer (TNF and/or chromophore) [13]. Absorption of a photon catapults an electron from the highest occupied molecular orbital (HOMO) of the sensitizer to the LUMO, followed by an electron transfer to the LiNbO₃ CB. Due to its size (20 nm in diameter) one particle can host several charges, thus, will act as a multi-electron trap. Accumulation of charges eventually leads to band bending and creation of recombination barriers (formation of potential wells), which hinder recombination with holes (Fig. 5, right). This will ultimately reduce the probability of geminate recombination and, thus, improve charge generation and transport. Thus LiNbO₃ NPs by themselves do not contribute to charge generation but they seem to enhance the photo-conductivity.

Now we check whether this model is capable of explaining our experimental observations. TNF and LiNbO₃ NP of sufficient concentration, they both enlarge the photoconductivity, as it is evident from Fig. 2. The model described above, stating that LiNbO₃ NP are very effective traps for electrons and hence increase the production of holes, easily explains the NP-induced increase of the conductivity. Charge generation probably takes place via light absorption by the PVK/TNF charge-transfer complex (materials A–I and R only) and by the chromophores (DMN-PAA/MNPAA) [22].

There is almost no influence of the NP on the steady-state over-modulation field (Fig. 3a), up to a threshold concentration of 10^{-3} wt.%. However, in the same range of con-



Fig. 5 Energy scheme of the PR composite containing $LiNbO_3$ NP. The band-bending effect and creation of the drift and recombination barriers is illustrated on the *right*

centrations we observe a pronounced increase of the TBC (Fig. 3b). Since the amplitude of the PR index modulation is almost unchanged, this must be attributed to a larger phase shift between index and light patterns. Larger transport lengths can explain this effect; again in accordance with the model explained earlier in the text that predicts improved hole transport [13]. Addition of TNF increases the photoconductivity as well but by putting more charge carriers into the system and not by increasing the transport lengths, thus leaving the TBC at smaller values.

Above LiNbO₃ NP contents of about 10^{-3} wt.%, the PR performance deteriorates with increasing NP content (Fig. 3). There are two reasons for this: first, for a NP content of about 1 wt.% the average separation distance *l* between particles becomes comparable to the Debye screening length ($l \approx r_D$) [13], thus, the space-charge field collapses because now almost all mobile holes generated in the volume of the composite are participating in screening of the charge separation which is necessary for observation of the photo-refractive effect. Second, the optical quality of the composite is diminished, i.e., light scattering increases.

Figure 4 reveals almost no dependence of the response time on the LiNbO₃ NP concentration. This is somehow surprising, since Fig. 2 clearly shows an increase of the photoconductivity by the addition of LiNbO₃ NP. Here one has to consider that Fig. 2 shows the AC conductivity at a modulation frequency of 10 Hz, while Fig. 4 shows time constants of the order of 1–20 s. Thus the AC conductivity where charge generation has a strong impact—is clearly influenced by the LiNbO₃ NP. The DC conductivity relevant for the dynamics of DFWM and TBC is obviously much less influenced by charge generation—there the LiNbO₃ NP influence mainly the transport length.

5 Conclusions

The aim of this work was the first study of a new class of hybrid materials, combining two of the most studied photorefractive systems. In DFWM and TBC experiments the PR properties of materials based on PVK sensitized with LiNbO₃ NP and TNF as well as with LiNbO₃ NP alone were studied and compared with those of the standard material sensitized with TNF. Photo-current and photo-refractive parameters were studied as a function of the LiNbO₃ NP concentration.

An impact of the LiNbO₃ NP is seen even for extremely low concentrations of 10^{-7} wt.%. We observed that in composites with low concentration of nano-particles (from 10^{-7} to 10^{-3} wt.%) the PR performance increases with the content of LiNbO₃. The optimum is reached at 10^{-3} wt.% LiNbO₃. For higher contents of NP (from 10^{-1} to 5 wt.%) the performance gradually worsens. We attribute this finding to Debye screening and light scattering due to aggregation of the nano-particles.

Acknowledgements The authors thank Elisabeth Soergel and Konrad Peithmann (University of Bonn) for helpful discussions. Dr. S. Mansurova thanks the Alexander von Humboldt Foundation for the financial support. Financial support by the German Research Foundation (DFG), European Space Agency (ESA), and the Deutsche Telekom AG is also gratefully acknowledged.

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